Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

# 2SK246

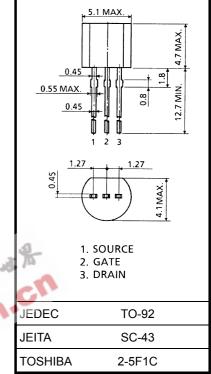
### For Constant Current, Impedance Converter and DC-AC High Input Impedance Amplifier Circuit Applications

- High breakdown voltage:  $V_{GDS} = -50 V$
- High input impedance:  $I_{GSS} = -1 nA (max) (V_{GS} = -30 V)$

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Gate-drain voltage	V <sub>GDS</sub>	-50	V	
Gate current	IG	10	mA	
Drain power dissipation	PD	300	mW	
Junction temperature	Тј	125	°C	
Storage temperature range	T <sub>stg</sub>	-55~125	°C	1.3

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



Weight: 0.21 g (typ.)

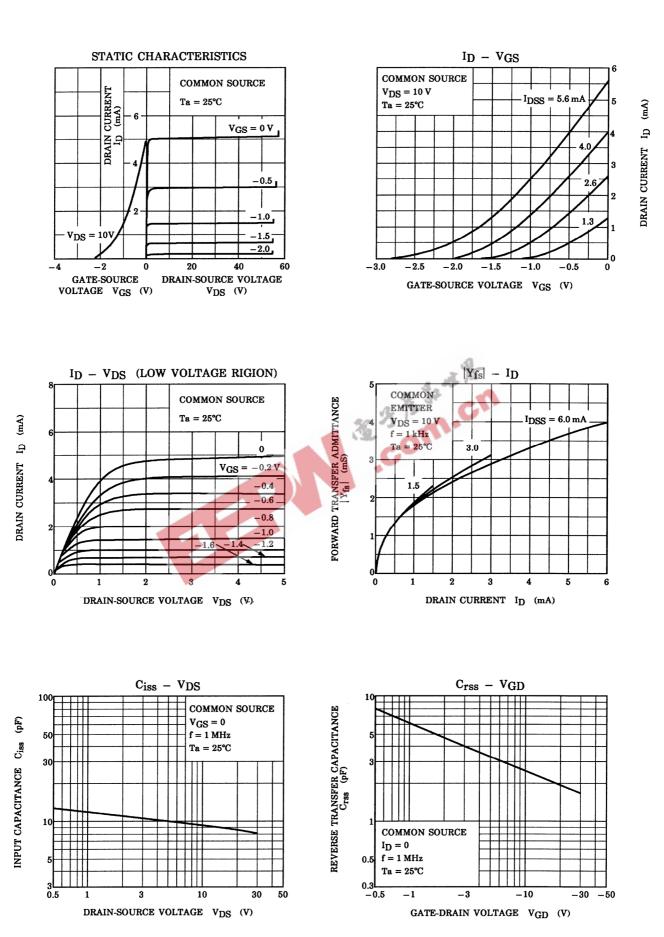
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling

Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

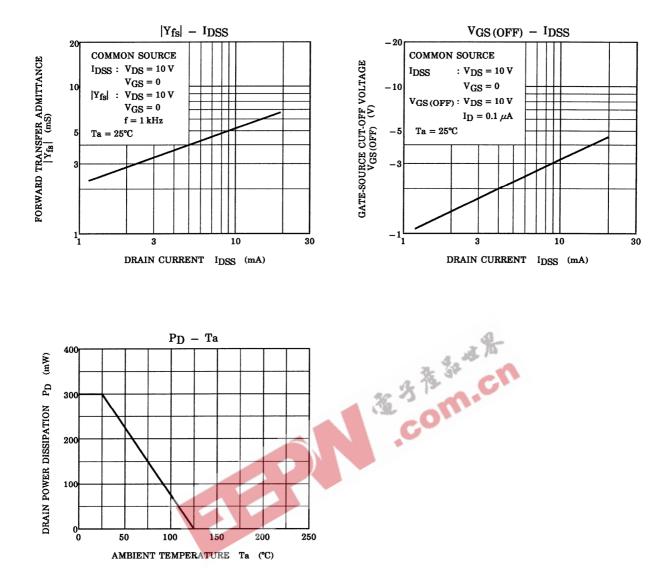
#### **Electrical Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate cut-off current	I <sub>GSS</sub>	$V_{GS} = -30 \text{ V}, \text{ V}_{DS} = 0$	_	_	-1.0	nA
Gate-drain breakdown voltage	V (BR) GDS	$V_{DS} = 0, I_G = -100 \ \mu A$	-50			V
Drain current	I <sub>DSS</sub> (Note)	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0$	1.2	_	14	mA
Gate-source cut-off voltage	V <sub>GS (OFF)</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 0.1 \mu\text{A}$	-0.7	_	-6.0	V
Forward transfer admittance	Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ kHz}$	1.5	_		mS
Input capacitance	C <sub>iss</sub>	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$	_	9.0	_	pF
Reverse transfer capacitance	C <sub>rss</sub>	$V_{DG} = 10 \text{ V}, \text{ I}_{D} = 0, \text{ f} = 1 \text{ MHz}$	_	2.5		pF

Note: I<sub>DSS</sub> classification Y: 1.2~3.0 mA, GR: 2.6~6.5 mA, BL: 6~14 mA



## **TOSHIBA**



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20070701-EN GENERAL

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